

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μ PA1804 is a switching device which can be driven directly by a 4.5 V power source.

The μ PA1804 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 4.5 V power source
- · Low on-state resistance $R_{DS(on)1} = 23 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 4.0 \text{ A})$ $R_{DS(on)2} = 32 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, \text{ ID} = 4.0 \text{ A})$
- Built-in G-S protection diode against ESD

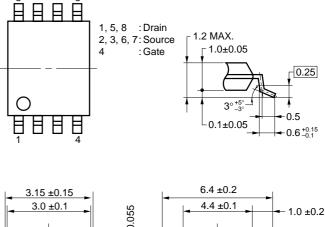
ORDERING INFORMATION

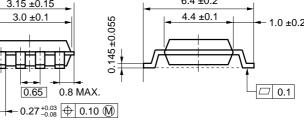
PART NUMBER	PACKAGE
μ PA1804GR-9JG	Power TSSOP8

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

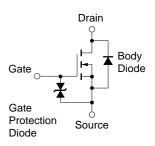
Drain to Source Voltage	VDSS	30	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	ID(DC)	±8.0	А
Drain Current (pulse) ^{Note1}	D(pulse)	±32	А
Total Power Dissipation Note2	Pτ	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

PACKAGE DRAWING (Unit : mm)





EQUIVALENT CIRCUIT



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Mounted on ceramic substrate of 5000 mm² x 1.1 mm
- Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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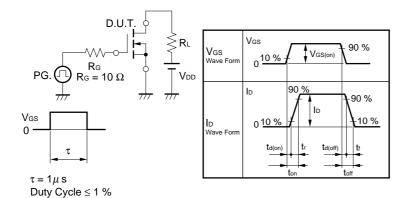
D13868EJ2V0DS00 (2nd edition) Document No. May 2001 NS CP(K) Date Published Printed in Japan

The mark ★ shows major revised points.

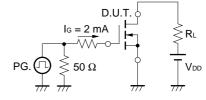
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vds = 30 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 16 V$, $V_{DS} = 0 V$			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	Vds = 10 V, Id = 1 mA	1.0	2.1	2.5	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = 10 V, I_{D} = 4.0 A$	3	8.7		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 10 V, I_D = 4.0 A$		18	23	mΩ
	RDS(on)2	$V_{GS} = 4.5 V, I_D = 4.0 A$		24	32	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		761		pF
Output Capacitance	Coss	Vgs = 0 V		258		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		99		pF
Turn-on Delay Time	td(on)	Vdd = 15 V		24		ns
Rise Time	tr	ID = 4.0 A		83		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = 10 V$		46		ns
Fall Time	tr	Rg = 10 Ω		29		ns
Total Gate Charge	QG	V _{DS} = 24 V		13.5		nC
Gate to Source Charge	QGS	ID = 8.0 A		2.4		nC
Gate to Drain Charge	Qgd	Vgs = 10 V		3.7		nC
Diode Forward Voltage	VF(S-D)	IF = 8.0 A, VGS = 0 V		0.86		V
Reverse Recovery Time	trr	IF = 8.0 A, VGS = 0 V		27		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>μ</i> s		16		nC

TEST CIRCUIT 1 SWITCHING TIME

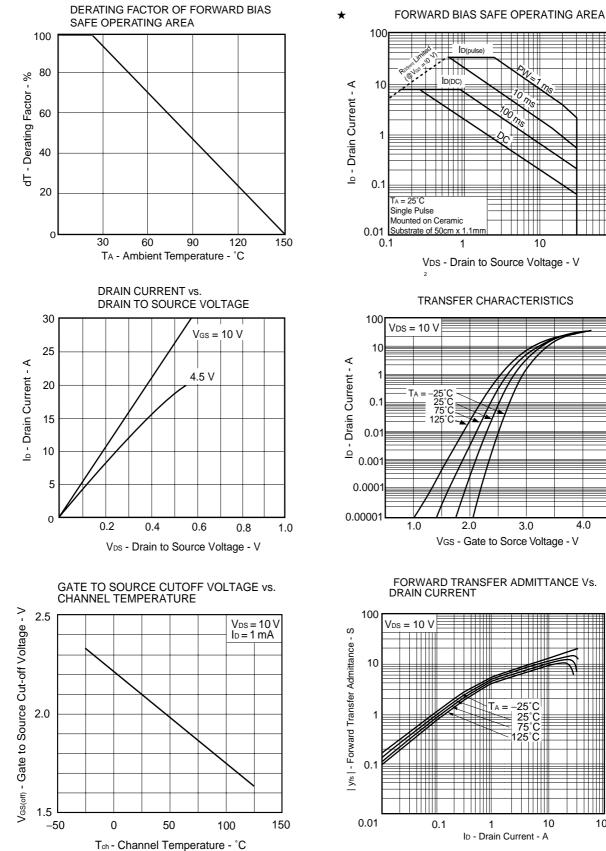


TEST CIRCUIT 2 GATE CHARGE



100



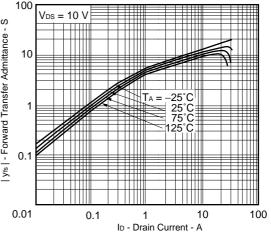




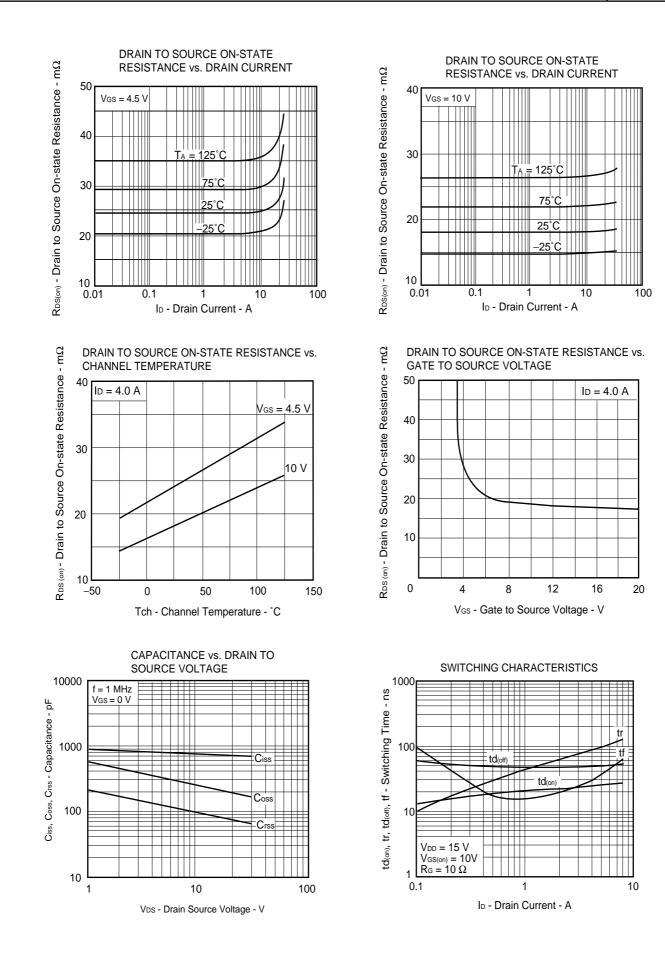
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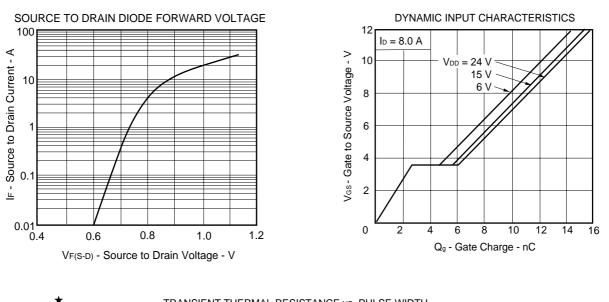
FORWARD TRANSFER ADMITTANCE Vs. DRAIN CURRENT

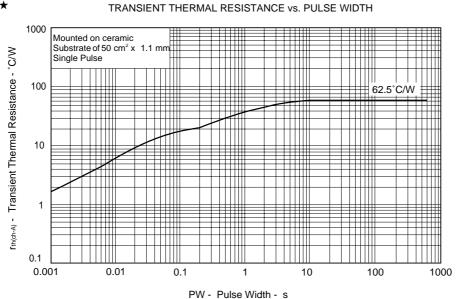


Data Sheet D13868EJ2V0DS



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